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TOSHIBA

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7SZ125AFE

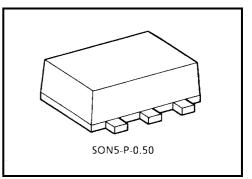
Dual Bus Buffer 3-State Output

Features

- High output drive: $\pm 24 \text{ mA} (\text{min}) @ \text{V}_{\text{CC}} = 3 \text{ V}$
- Super high speed operation: t_{pd} 2.6 ns (typ.) @V_{CC} = 5 V, 50pF
- Operation voltage range: $V_{CC (opr)} = 1.8 \sim 5.5 \text{ V}$
- Latch-up performance: ±500 mA or more
- ESD performance: ±200 V or more (JEITA)

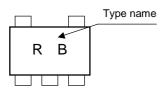
 ± 2000 V or more (MIL)

- Power down protection is provided on all inputs and outputs.
- Matches the performance of TC74LCX series when operated at 3.3 V VCC.

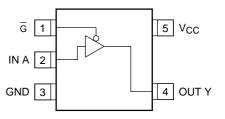


Weight: 0.003 g (typ.)

Marking



Pin Assignment (top view)



Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Power supply voltage	V _{CC}	-0.5~6	V
DC input voltage	V _{IN}	-0.5~6	V
DC output voltage	V _{OUT}	$-0.5 \sim V_{CC} + 0.5$	V
Input diode current	I _{IK}	-20	mA
Output diode current	lok	±20	mA
DC output current	lout	±50	mA
DC V _{CC} /ground current	ICC	±50	mA
Power dissipation	PD	150	mW
Storage temperature	T _{stg}	-65~150	°C
Lead temperature (10s)	ΤL	260	°C

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А	IG	Y
Х	Н	Z
L	L	L
Н	L	Н



Logic Diagram

Recommended Operating Conditions

Characteristics	Symbol	Rating	Unit			
Supply voltage	Vee	1.8~5.5	V			
Supply vollage	VCC	V _{CC} 1.5~5.5 (Note)				
Input voltage	V _{IN}	0~5.5	V			
Output voltage	V _{OUT}	0~V _{CC}	V			
Operating temperature	T _{opr}	-40~85	°C			
		0~20 (V_{CC} = 1.8 V, 2.5 V \pm 0.2 V)				
Input rise and fall time	dt/dv	0~10 (V_{CC} = 3.3 V \pm 0.3 V)	ns/V			
		0~5 (V_{CC} = 5.5 V \pm 0.5 V)				

Note: Data retention only

www.DataSheet4U.com Electrical Characteristics

DC Characteristics

Characteristics Symbol		Symbol	Test Condition			Ta = 25°C			Ta = -40~85°C		Unit
		V _{CC} (V)		Min	Тур.	Max	Min	Max	Unit		
				1.8	$\begin{array}{c} 0.75 \times \\ V_{CC} \end{array}$			$_{V_{CC}}^{0.75\times}$	_		
	High level			2.3~5.5	$0.7 \times V_{CC}$	_	_	$0.7 \times V_{CC}$	_		
Input voltage					1.8			$_{V_{CC}}^{0.25\times}$	_	$\begin{array}{c} 0.25 \times \\ V_{CC} \end{array}$	V
	Low level	VIL			2.3~5.5	_	_	$0.3 \times V_{CC}$	—	$0.3 \times V_{CC}$	
					1.8	1.7	1.8	_	1.7	_	
				I _{OH} = –100 μA	2.3	2.2	2.3		2.2	_	
				IOH 100 μA	3.0	2.9	3.0		2.9	_	
	High level	V _{ОН}	V _{IN} = V _{IH} or V _{IL}		4.5	4.4	4.5	_	4.4	_	
	riigirievei	⊻он		I _{OH} = -8 mA	2.3	1.9	2.15	_	1.9	_	- V
				I _{OH} = -16 mA	3.0	2.4	2.8		2.4	_	
				I _{OH} = -24 mA	3.0	2.3	2.68	_	2.3	_	
Output voltage				I _{OH} = -32 mA	4.5	3.8	4.2	_	3.8	_	
Output voltage				I _{OL} = 100 μA	1.8		0	0.1		0.1	
					2.3		0	0.1		0.1	
					3.0		0	0.1		0.1	
	Low level	V _{OL}	V _{IN} = V _{IH}		4.5		0	0.1	_	0.1	
	LOWICVCI		VIN = VIH	I _{OL} = 8 mA	2.3		0.1	0.3	_	0.3	
				I _{OL} = 16 mA	3.0		0.15	0.4		0.4	-
				I _{OL} = 24 mA	3.0		0.22	0.55		0.55	
			I _{OL} = 32 mA	4.5		0.22	0.55		0.55		
Input leakage curre	ent	I _{IN}	$V_{IN} = 5.5 V \text{ or GND}$		0~5.5			±1		±10	μA
3-state output off-s	tate current	I _{OZ}			1.8~5.5	_		±1	_	±10	μA
Power off leakage	current	IOFF	V_{IN} or $V_{OUT} = 5.5 V$		0.0		_	1		10	μA
Quiescent supply of	urrent	ICC	$V_{IN} = 5.5 V \text{ or GND}$		5.5			2		20	μA

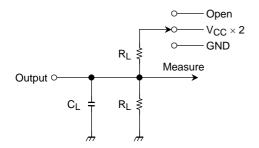
www.DataSheet4U.com AC Characteristics (unless otherwise specified, Input: $t_r = t_f = 3$ ns)

Characteristics	teristics Symbol Test Condition			Ta = 25°C			Ta = -40~85°C		Unit
Charactenstics	Symbol	Test Condition	V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit
		$C_L = 15 \text{ pF}, \text{ R}_L = 1 \text{ M}\Omega$	1.8	2.0	5.3	11.0	2.0	11.5	ns
			2.5 ± 0.2	0.8	3.4	7.5	0.8	8.0	
Propagation delay time	t _{pLH}		$\textbf{3.3}\pm\textbf{0.3}$	0.5	2.5	5.2	0.5	5.5	
Propagation delay time	t _{pHL}		5.0 ± 0.5	0.5	2.1	4.5	0.5	4.8	
		$C_{1} = 50 \text{ pc}$ $R_{1} = 500 \text{ C}$	$\textbf{3.3}\pm\textbf{0.3}$	1.5	3.2	5.7	1.5	6.0	
		$C_L = 50 \text{ pF}, R_L = 500 \Omega$	5.0 ± 0.5	0.8	2.6	5.0	0.8	5.3	
			1.8	2.0	7.0	12.5	2.0	13.0	ns
Output enable time	t _{pZL}	$C_L = 50 \text{ pF}, R_L = 500 \Omega$	$\textbf{2.5}\pm\textbf{0.2}$	1.5	4.6	8.5	1.5	9.0	
	t _{pZH}		$\textbf{3.3}\pm\textbf{0.3}$	1.5	3.5	6.2	1.5	6.5	
			5.0 ± 0.5	0.8	2.8	5.5	0.8	5.8	
		$C_L = 50 \text{ pF}, R_L = 500 \Omega$	1.8	2.0	5.4	11.0	2.0	12.0	
Output disable time	t _{pLZ}		2.5 ± 0.2	1.5	3.5	8.0	1.5	8.5	ns
	t _{pHZ}		$\textbf{3.3}\pm\textbf{0.3}$	1.0	2.8	5.7	1.0	6.0	
			5.0 ± 0.5	0.5	2.1	4.7	0.5	5.0	
Input capacitance	C _{IN}		0~5.5		4	_	—	—	pF
Power dissipation	C _{PD}	(Note)	3.3		20			—	рF
capacitance	OPD	(10018)	5.5		27	_		_	

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation: $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

AC Characteristics Measurement Circuit



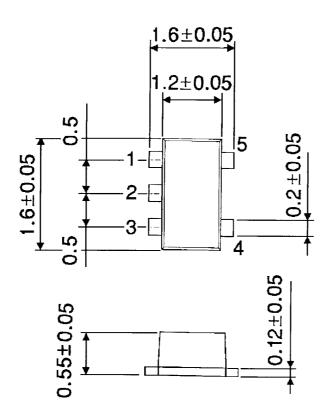
Characteristics	Switch
t _{pLH} , t _{pHL}	Open
t _{pLZ} , t _{pZL}	$V_{CC} imes 2$
^t pHZ, ^t pZH	GND



www.DataSheet4U.com Package Dimensions

SON5-P-0.50

Unit : mm



Weight: 0.003 g (typ.)



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RESTRICTIONS ON PRODUCT USE

Handbook" etc..

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